

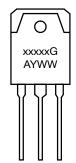
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

DATE 30 OCT 2007

- 2. CONTROLLING DIMENSION: MILLIMETERS
 3. DIMENSION b APPLIES TO PLATED TERMINAL
 AND IS MEASURED BETWEEN 0.15 AND 0.30mm
 FROM THE TERMINAL TIP.
- 4. DIMENSION A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	19.70	19.90	20.10
В	15.40	15.60	15.80
С	4.60	4.80	5.00
D	0.80	1.00	1.20
Е	1.45	1.50	1.65
F	1.80	2.00	2.20
G	5.45 BSC		
Н	1.20	1.40	1.60
J	0.55	0.60	0.75
K	19.80	20.00	20.20
L	18.50	18.70	18.90
P	3.30	3.50	3.70
Q	3.10	3.20	3.50
U	5.00 REF		
W	2.80	3.00	3.20

GENERIC MARKING DIAGRAM*



xxxxx = Specific Device Code
G = Pb-Free Package
A = Assembly Location
Y = Year

Y = Year WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

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- 2. COLLECTOR
- 3. EMITTER 4. COLLECTOR
- R

STYLE 2:

2.

2: ANODE CATHODE ANODE

CATHODE

- STYLE 3: PIN 1. 2. 3.
 - PIN 1. GATE 2. DRAIN 3. SOURCE

DRAIN